RENESAS

HVC375B

Variable Capacitance Diode for VCO

REJ03G0064-0100Z (Previous: ADE-208-625) Rev.1.00 Jul.24.2003

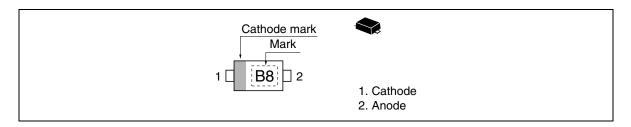
Features

- Narrow terminal Capacitance deviation.
- Low series resistance. ($r_s = 1.1 \Omega max$)
- Good C-V linearity.
- Ultra small Flat Package (UFP) is suitable for surface mount design.

Ordering Information

| Туре No. | Laser Mark | Package Code | |
|----------|------------|--------------|--|
| HVC375B | B8 | UFP | |

Pin Arrangement





Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Value | Unit | |
|----------------------|----------------|-------------|------|--|
| Reverse voltage | V _R | 10 | V | |
| Junction temperature | Tj | 125 | °C | |
| Storage temperature | Tstg | -55 to +125 | °C | |

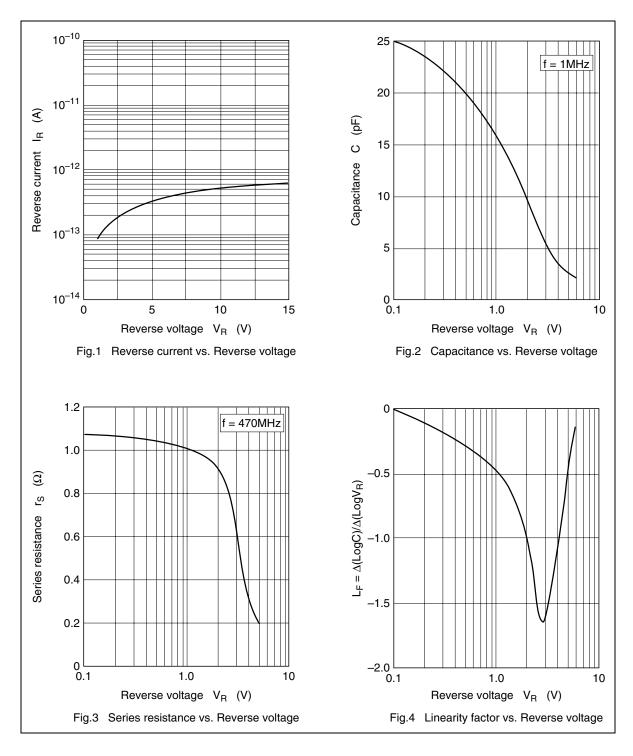
Electrical Characteristics

 $(Ta = 25^{\circ}C)$

| Item | Symbol | Min | Тур | Max | Unit | Test Condition |
|-------------------|-----------------------|------|-----|------|------|--|
| Reverse current | I _{R1} | _ | | 10 | nA | V _R = 10 V |
| | I _{R2} | | | 100 | | $V_{_{\rm R}} = 10 \text{ V}, \text{ Ta} = 60^{\circ}\text{C}$ |
| Capacitance | C ₁ | 15.0 | _ | 16.5 | pF | $V_{_{\mathrm{R}}} = 1 \text{ V}, \text{ f} = 1 \text{ MHz}$ |
| | C ₃ | 5.0 | | 6.0 | _ | $V_{_{\mathrm{R}}}$ = 3 V, f = 1 MHz |
| | C ₄ | 3.3 | | 4.0 | _ | $V_{_{\mathrm{R}}}$ = 4 V, f = 1 MHz |
| Capacitance ratio | n | 4.0 | _ | | _ | C ₁ / C ₄ |
| Series resistance | r _s | | _ | 1.1 | Ω | V _R = 2 V, f = 470 MHz |



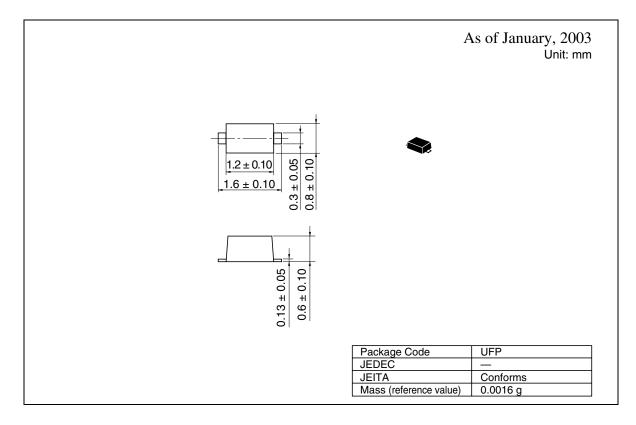
Main Characteristic





HVC375B

Package Dimensions





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Keep safety first in your circuit designs!

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